

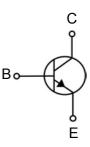
Feartures

- Ideally suited for automatic insertion
- For Switching and AF Amplifier Applications



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
NSVBC847BTT1G	SOT-523	1F	3000



Maximum Ratings (Ta=25°C unless otherwise noted)

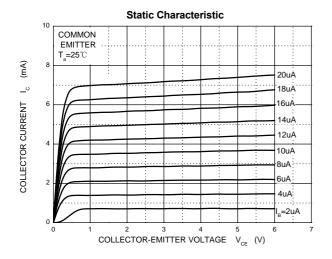
Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	I _c	0.1	Α
Collector Power Dissipation	P _C	150	mW
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55∼+150	°C

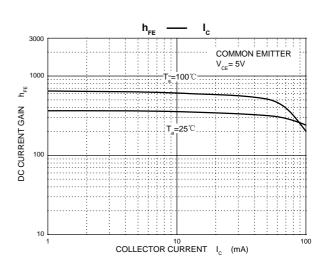


Electrical Characteristics (Ta=25°C unless otherwise specified)

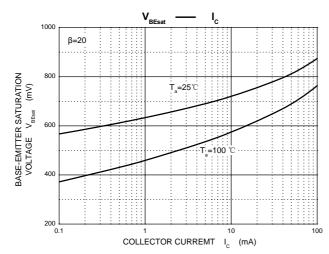
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 10μΑ, I _E =0	50			V	
Collector-emitter breakdown voltage	V _{(BR)CEO}	CEO I _C = 10mA, I _B =0				V	
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_{E}= 1 \mu A, I_{C}=0$	6			٧	
Collector Cutoff Current	I _{CBO}	V _{CB} =30V			15	nA	
DC current gain	h _{FE}	V_{CE} = 5V, I_{C} = 2mA	200		450		
Collector emitter esturation valtage	1/	I _C =10mA, I _B =0. 5mA			0.25	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C=100$ mA, $I_B=5$ mA			0.6	V	
Page emitter acturation voltage	V _{BE(sat)}	I _C =10mA, I _B =0. 5mA		0.7		V	
Base-emitter saturation voltage		$I_C=100$ mA, $I_B=5$ mA		0.9			
Page emitter voltage	V _{BE(on)}	V_{CE} = 5V, I_{C} = 2mA	580	660	700	mV	
Base-emitter voltage		V_{CE} = 5V, I_{C} = 10mA			770	IIIV	
Transition fraguency	f _⊤	V_{CE} = 5 V_{IC} = 10mA	100			MHz	
Transition frequency		f=100MHz	100			IVIITIZ	
Collector output capacitance	C _{ob}	V _{CB} =10V,f=1MHz		4.5	pF		
N	NF	V _{CE} =5V,f=1kHz,			10	dB	
Noise figure		$R_S=2k\Omega$,BW=200Hz					

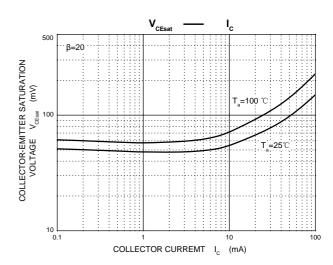
Typical Characteristics

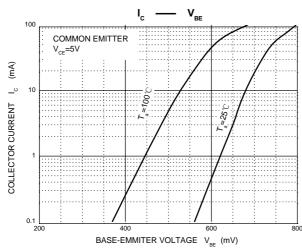


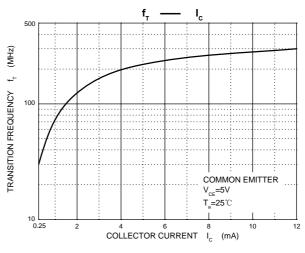


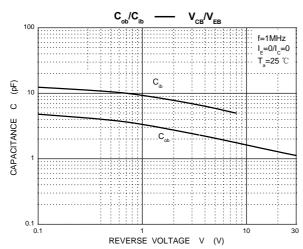


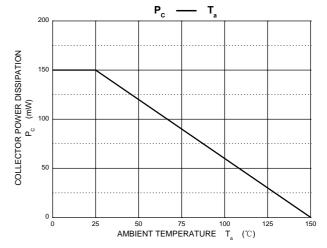






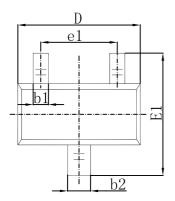


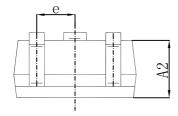


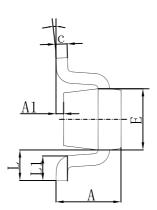




SOT-523 Package Information

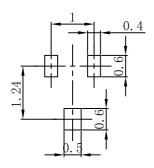






Symbol	Dimensions In Millimeters		Dimensions In Inches			
	Min.	Max.	Min.	Max.		
Α	0.700	0.900	0.028	0.035		
A1	0.000	0.100	0.000	0.004		
A2	0.700	0.800	0.028	0.031		
b1	0.150	0.250	0.006	0.010		
b2	0.250	0.350	0.010	0.014		
С	0.100	0.200	0.004	0.008		
D	1.500	1.700	0.059	0.067		
E	0.700	0.900	0.028	0.035		
E1	1.450	1.750	0.057	0.069		
е	0.500	0.500 TYP.		0.020 TYP.		
e1	0.900	1.100	0.035	0.043		
L	0.400 REF.		0.016 REF.			
L1	0.260	0.460	0.010	0.018		
θ	0°	8°	0°	8°		

SOT-523 Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

NSVBC847BTT1G NPN Plastic-Encapsulate Transistors

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